

PIN Silicon Photodiode

OP993, OP999



Features:

- Choice of TO-18 (OP993) or T-1¾ package (OP999)
- Small package style ideal for space-limited applications
- Linear response vs. irradiance
- Fast switching time
- Choice of narrow or wide receiving angle

Description:

Each **OP993** and **OP999** device consists of a PIN silicon photodiode molded in a dark blue injection molded shell package that provides excellent optical and mechanical axis alignment, optical lens surface, control of chip placement and consistency of the outside package dimensions.

OP993 has a TO-18 package style and a *wide* receiving angle that provides excellent on-axis coupling. **OP999** has a T-1¾ package style and a *narrow* receiving angle that provides excellent on-axis coupling.

Both devices are 100% production tested for close correlation with OPTEK GaAIAs emitters.

Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

Applications:

- Non-contact reflective object sensor
- Assembly line automation
- Machine automation
- Machine safety
- End of travel sensor
- Door sensor

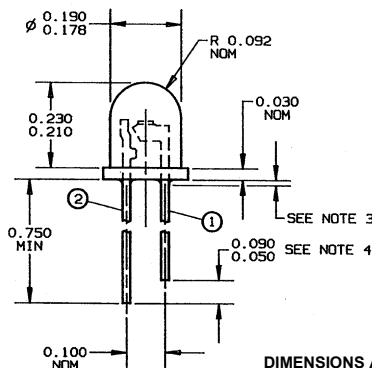
| Ordering Information | | | |
|----------------------|------------|---------------|-------------|
| Part Number | Sensor | Viewing Angle | Lead Length |
| OP993 | Photodiode | 118° | 0.75 min |
| OP999 | Photodiode | 18° | |

OP993

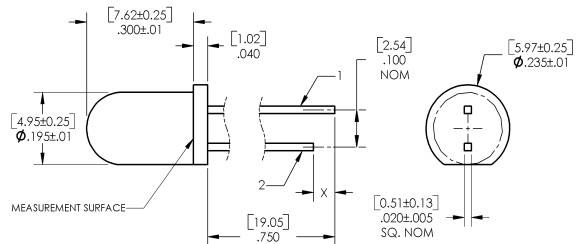


| Pin # | Sensor |
|-------|---------|
| 1 | Cathode |
| 2 | Anode |

OP993



OP999



OP999



| Pin # | Sensor |
|-------|---------|
| 1 | Anode |
| 2 | Cathode |

CONTAINS POLYSULFONE

To avoid stress cracking, we suggest using ND Industries' **Vibra-Tite** for thread-locking. **Vibra-Tite** evaporates fast without causing structural failure in OPTEK'S molded plastics.



General Note
TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

OPTEK Technology, Inc.
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www.optekinc.com | www.ttelectronics.com

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Electrical Specifications

| Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ unless otherwise noted) | |
|--|---|
| Reverse Breakdown Voltage | 60 V |
| Storage & Operating Temperature Range | -40°C to $+100^\circ\text{C}$ |
| Lead Soldering Temperature [1/16 inch (1.6 mm) from the case for 5 sec. with soldering iron] | $260^\circ\text{C}^{(1)}$ |
| Reverse Breakdown Voltage | 60 V |
| Power Dissipation | $100\text{ mW}^{(2)}$ |

| Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted) | | | | | | |
|---|---------------------------|------|-----|------|---------------|--|
| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
| I_L | Reverse Light Current | | | | | |
| | OP993 | 12.5 | - | 28.5 | μA | $V_R = 5\text{ V}, E_E = 1.7\text{ mW/cm}^2^{(3)}$ |
| | OP999 | 6.5 | - | 15 | | $V_R = 5\text{ V}, E_E = 0.25\text{ mW/cm}^2^{(3)}$ |
| I_D | Reverse Dark Current | | 1 | 60 | nA | $V_R = 30\text{ V}, E_E = 0^{(4)}$ |
| $V_{(BR)}$ | Reverse Breakdown Voltage | 60 | | | V | $I_R = 100\ \mu\text{A}$ |
| V_F | Forward Voltage | | | 1.2 | V | $I_F = 1\text{ mA}$ |
| C_T | Total Capacitance | | 4 | | pF | $V_R = 20\text{ V}, E_E = 0, f = 1.0\text{ MHz}$ |
| t_r | Rise Time | | 5 | | ns | $V_R = 20\text{ V}, \lambda = 850\text{ nm}, R_L = 50\ \Omega$ |
| t_f | Fall Time | | 5 | | | |

Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering. A maximum of 20 grams force may be applied to leads when soldering.
- (2) Derate linearly $1.67\text{ mW}/^\circ\text{C}$ above 25°C .
- (3) Light source is an unfiltered GaAlAs emitting diode operating at peak emission wavelength of 890 nm and $E_{E(APT)}$ of 1.7 mW/cm^2 for OP993 and 0.25 mW/cm^2 for OP999 average within a 0.25" diameter aperture.
- (4) This dimension is held to within $\pm 0.005''$ on the flange edge and may vary up to $\pm 0.020''$ in the area of the leads.

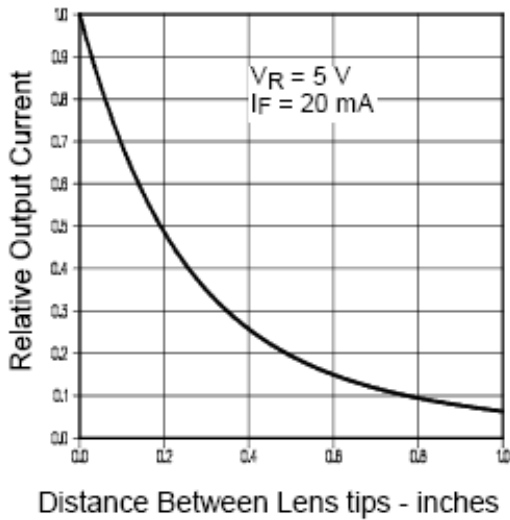
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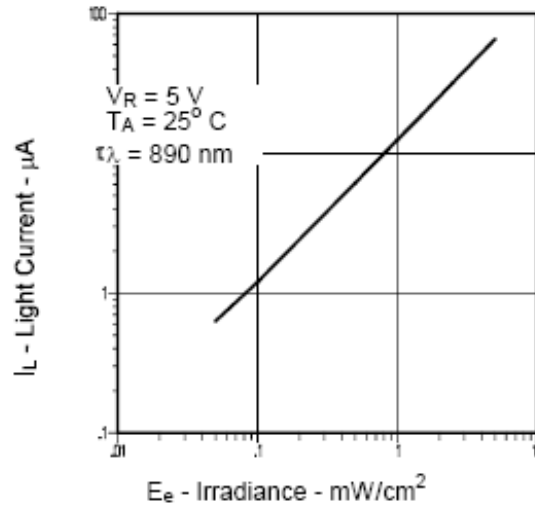


OP993

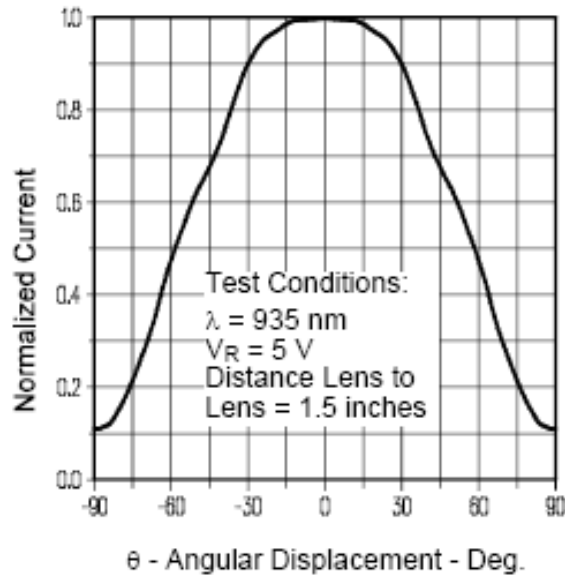
**Coupling Characteristics
OP993 and OP293**



Light Current vs. Irradiance



Light Current vs. Angular Displacement



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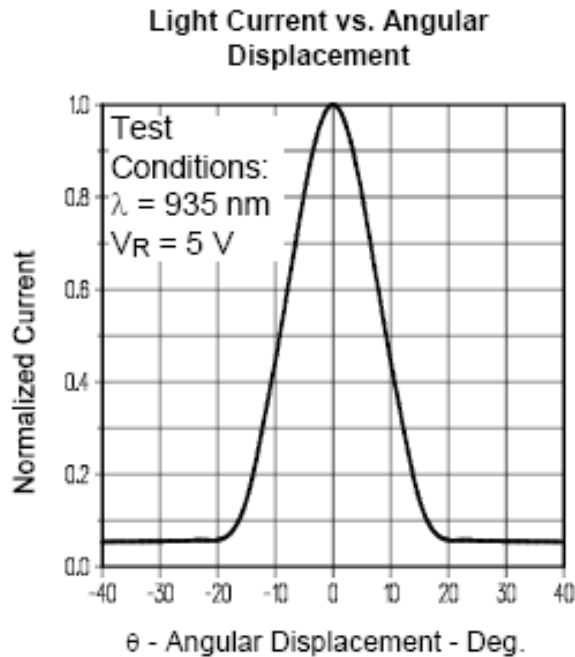
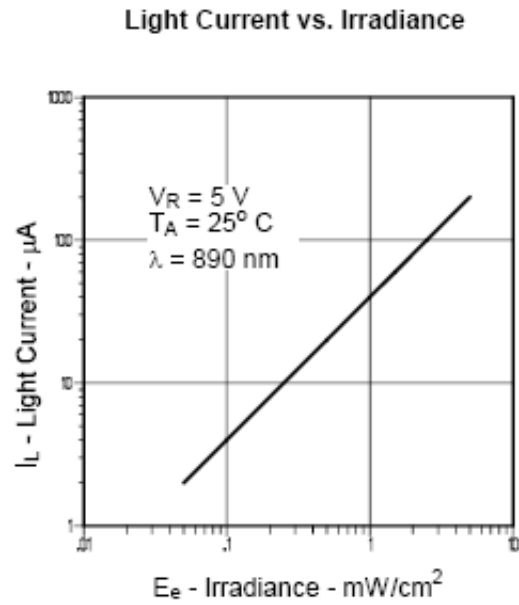
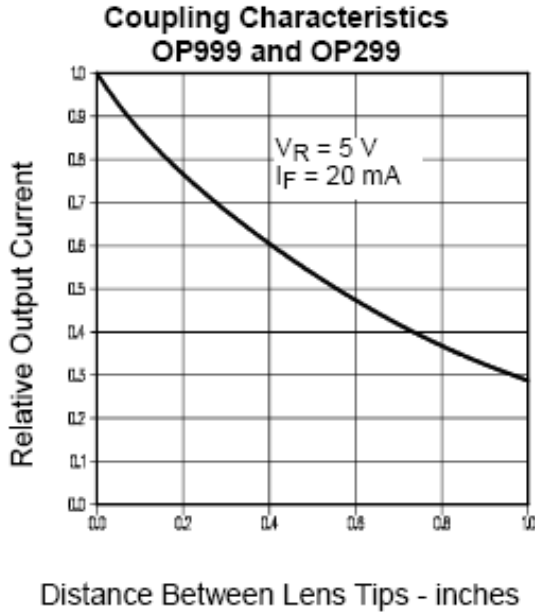
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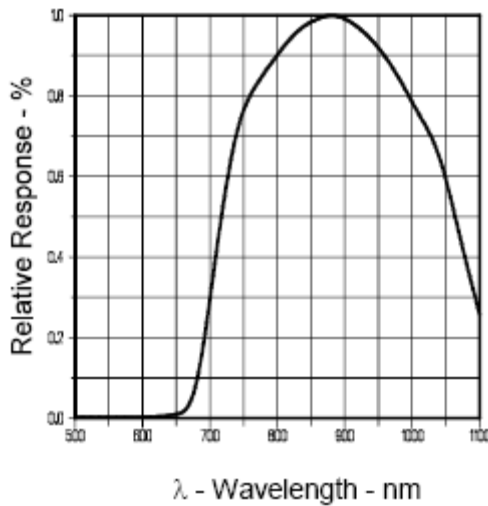


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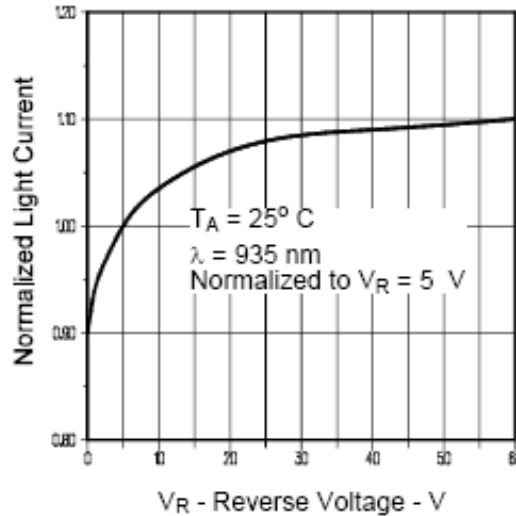
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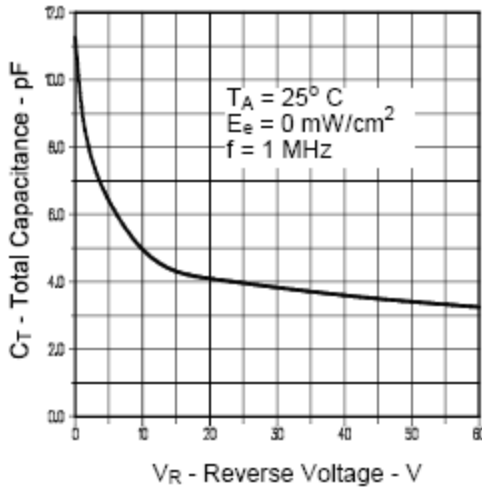
Relative Response vs. Wavelength



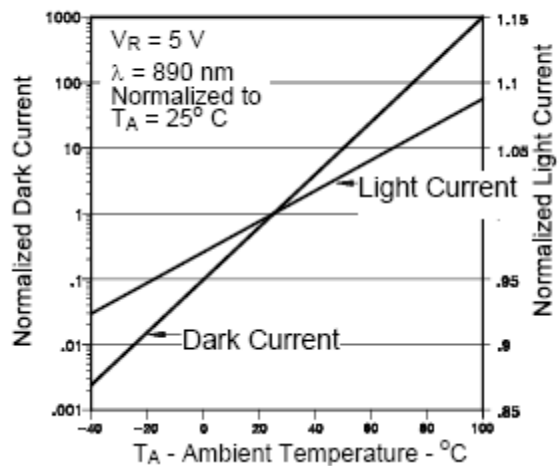
Normalized Light Current vs Reverse Voltage



Total Capacitance vs Reverse Voltage



Normalized Light and Dark Current vs Ambient Temperature



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